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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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## MOS FIELD EFFECT TRANSISTOR 2SK4212

### SWITCHING N-CHANNEL POWER MOS FET

#### **DESCRIPTION**

The 2SK4212 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

#### **FEATURES**

• Low on-state resistance

 $R_{DS(on)1} = 7.8 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = 10 \text{ V, Ip} = 30 \text{ A)}$ 

 $R_{DS(on)2} = 14 \text{ m}\Omega \text{ MAX}. \text{ (Vgs} = 4.5 \text{ V, Ip} = 20 \text{ A)}$ 

• Low total gate charge

 $Q_G = 27 \text{ nC TYP.}$  ( $V_{DD} = 15 \text{ V}$ ,  $V_{GS} = 10 \text{ V}$ ,  $I_D = 30 \text{ A}$ )

- 4.5 V drive available
- Avalanche capability ratings

#### **ORDERING INFORMATION**

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
2SK4212-ZK-E1-AY Note	Pure Sn (Tin)	Tape 2500 p/reel	TO 252 (MD 27K) hm 0 27 ~
2SK4212-ZK-E2-AY Note			TO-252 (MP-3ZK) typ. 0.27 g

Note Pb-free (This product does not contain Pb in external electrode).

#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	25	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	I <sub>D(DC)</sub>	±48	Α
Drain Current (pulse) Note1	ID(pulse)	±144	Α
Total Power Dissipation (Tc = 25°C)	P <sub>T1</sub>	35	W
Total Power Dissipation (T <sub>A</sub> = 25°C)	P <sub>T2</sub>	1.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	17	Α
Single Avalanche Energy Note2	Eas	28.9	mJ

**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

2. Starting T<sub>ch</sub> = 25°C, V<sub>DD</sub> = 12.5 V, R<sub>G</sub> = 25  $\Omega$ , V<sub>GS</sub> = 20  $\rightarrow$  0 V, L = 0.1 mH



(TO-252)

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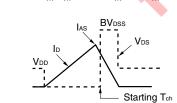
#### **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

CHARACTERISTICS	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current IDSS VDS = 25 V, VGS = 0 V		V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V			10	μA
Gate Leakage Current	Igss	V <sub>GS</sub> = ±16 V, V <sub>DS</sub> = 0 V			±100	nA
Gate to Source Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA	1.5		3.0	V
Forward Transfer Admittance Note	yfs	V <sub>DS</sub> = 5 V, I <sub>D</sub> = 12 A	10	22		S
Drain to Source On-state Resistance Note	RDS(on)1	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 30 A		5.5	7.8	mΩ
	R <sub>DS(on)2</sub>	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 20 A		8.5	14	mΩ
Input Capacitance C <sub>iss</sub> V <sub>DS</sub> = 15 V,			1200		pF	
Output Capacitance	Coss	V <sub>GS</sub> = 0 V,		220		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		140		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 15 V, I <sub>D</sub> = 30 A,		16		ns
Rise Time	tr	V <sub>GS</sub> = 10 V,		14		ns
Turn-off Delay Time	t <sub>d(off)</sub>	$R_G = 3 \Omega$		45		ns
Fall Time	tf			11		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = 15 V,		27		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = 10 V,		4		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = 30 A		7		nC
Body Diode Forward Voltage Note	V <sub>F(S-D)</sub>	IF = 30 A, VGS = 0 V		0.88	1.5	V
Reverse Recovery Time	trr	IF = 30 A, VGS = 0 V,		26		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		14		nC

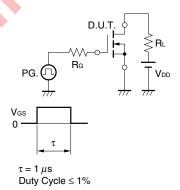
Note Pulsed

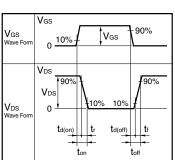
#### TEST CIRCUIT 1 AVALANCHE CAPABILITY

# $\begin{array}{c} \text{D.U.T.} \\ \text{Rg} = 25 \ \Omega \\ \text{Vgs} = 20 \rightarrow 0 \ \text{V} \end{array} \begin{array}{c} \text{D.U.T.} \\ \text{FG.} \\ \text{Vpb} \end{array}$

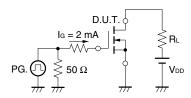


#### TEST CIRCUIT 2 SWITCHING TIME



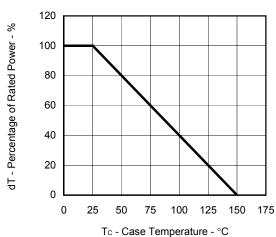


#### **TEST CIRCUIT 3 GATE CHARGE**

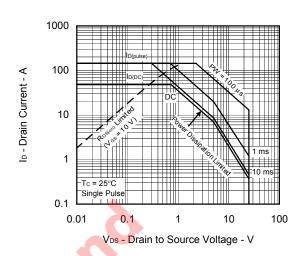


#### TYPICAL CHARACTERISTICS (TA = 25°C)

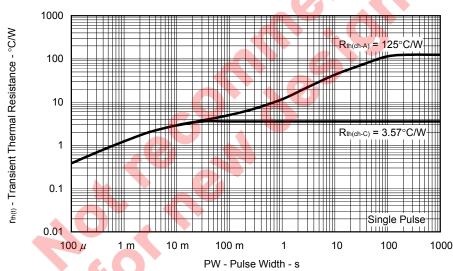




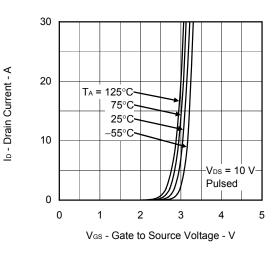
#### FORWARD BIAS SAFE OPERATING AREA



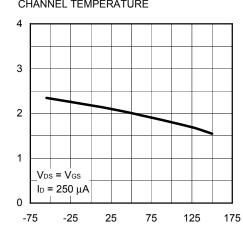
#### TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



#### FORWARD TRANSFER CHARACTERISTICS

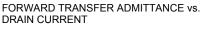


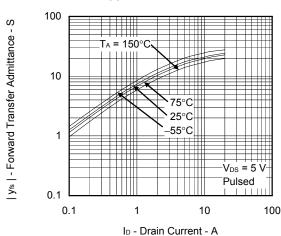
GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE



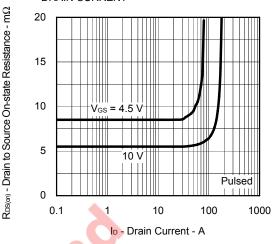
 $T_{\text{ch}}$  - Channel Temperature -  $^{\circ}C$ 

Ves(th) - Gate to Source Threshold Voltage - V

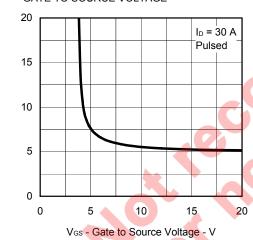




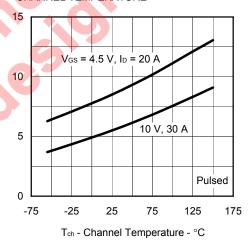
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



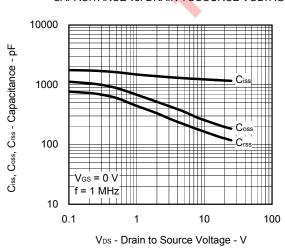
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



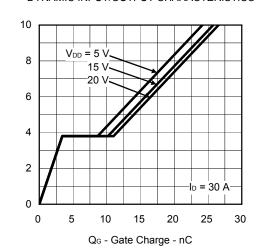
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



#### CAPACITANCE vs. DRAIN TOSOURCE VOLTAGE



DYNAMIC INPUT/OUTPUT CHARACTERISTICS

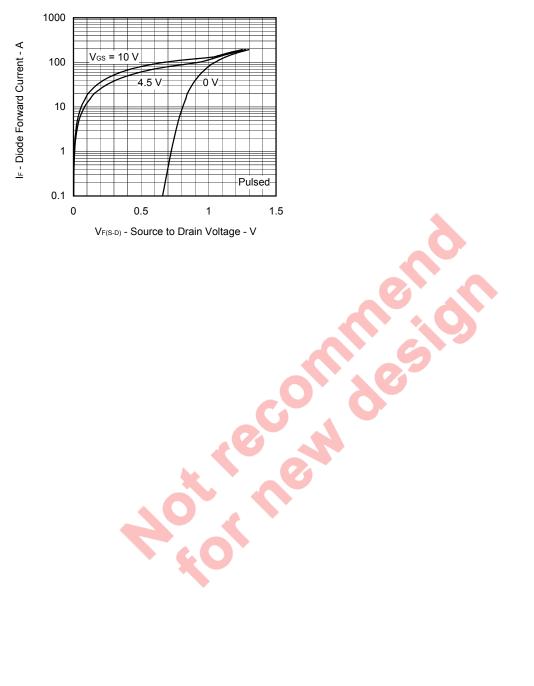


RDS(on) - Drain to Source On-state Resistance - m\Omega

R<sub>DS(on)</sub> - Drain to Source On-state Resistance - mΩ

Ves - Gate to Source Voltage - V

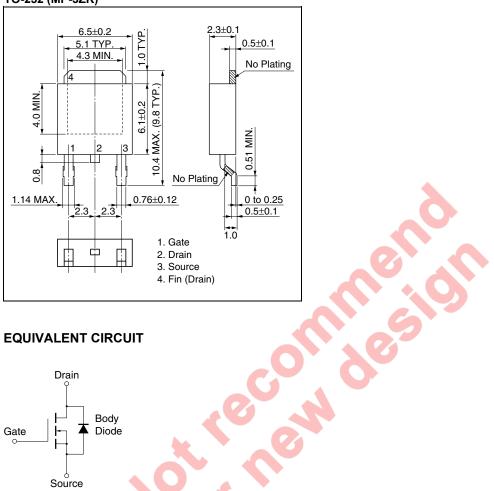
#### SOURCE TO DRAIN DIODE FORWARD VOLTAGE



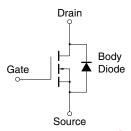
Data Sheet D19564EJ1V0DS

#### PACKAGE DRAWINGS (Unit: mm)

#### TO-252 (MP-3ZK)



#### **EQUIVALENT CIRCUIT**



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

Data Sheet D19564EJ1V0DS

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